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## Vishay Semiconductors

# Hyperfast Rectifier, 3 A FRED Pt®





### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	3 A			
$V_{R}$	100 V			
V <sub>F</sub> at I <sub>F</sub>	0.74 V			
t <sub>rr</sub>	30 ns			
T <sub>J</sub> max.	175 °C			
Package	SlimSMA (DO-221AC)			
Circuit configuration	Single			

#### **FEATURES**

 Hyperfast recovery time, reduced Q<sub>rr</sub>, and soft recovery

• 175 °C maximum operating junction temperature

Low forward voltage drop

· Low leakage current

• Specific for output and snubber operation

 Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

• Meets JESD 201 class 2 whisker test

 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in snubber, boost, lighting, as high frequency rectifiers and freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

### **MECHANICAL DATA**

Case: SlimSMA (DO-221AC)

Molding compound meets UL 94 V-0 flammability rating **Terminals:** matte tin plated leads, solderable per

J-STD-002

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	$V_{RRM}$		100	V
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 145 °C <sup>(1)</sup>	3	Δ.
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	85	А
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C

#### Note

(1) Device on PCB with 8 mm x 16 mm soldering lands

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	100	-	-	
Forward voltage	V	I <sub>F</sub> = 3 A	-	0.86	0.93	V
	V <sub>F</sub>	I <sub>F</sub> = 3 A, T <sub>J</sub> = 125 °C	-	0.74	0.78	
Reverse leakage current		V <sub>R</sub> = V <sub>R</sub> rated	-	-	2	
	IR	T <sub>J</sub> = 125 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	0.5	8	μA
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 100 V	-	13	-	pF



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	26	-	
Reverse recovery time t <sub>rr</sub>		I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, I <sub>rr</sub> = 0.25 A		-	-	30	ns
	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 3 A	-	18	-		
	T <sub>J</sub> = 125 °C		-	26	-		
Peak recovery current I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	2.5	-	^	
	IRRM	T <sub>J</sub> = 125 °C	$dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 160 \text{ V}$	-	4	-	Α
Reverse recovery charge Q <sub>rr</sub>	0	T <sub>J</sub> = 25 °C		-	23	-	nC
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	50	-	

THERMAL - MECHANICAL SPECIFICATIONS (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C
Thermal resistance, junction to mount	R <sub>thJM</sub>	Device mounted on PCB with 8 mm x 16 mm soldering lands	-	8	10	°C/W
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Device mounted on PCB with 2 mm x 3.5 mm soldering lands	-	91	110	C/VV
Approximate Weight				0.032		g
Approximate Weight				0.0011		OZ.
Marking device		Case style SlimSMA (DO-221AC)		31	<del>-</del> 11	

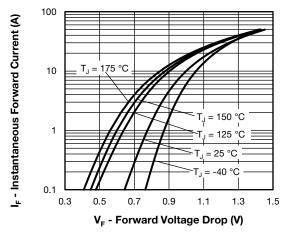


Fig. 1 - Typical Forward Voltage Drop Characteristics

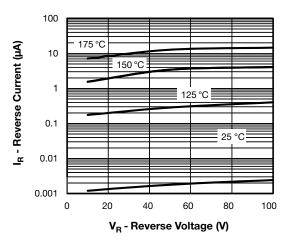


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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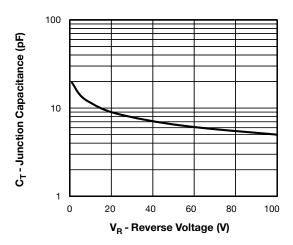


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

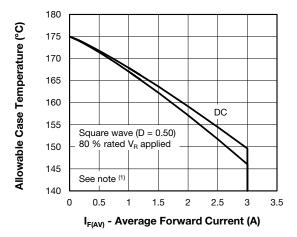


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

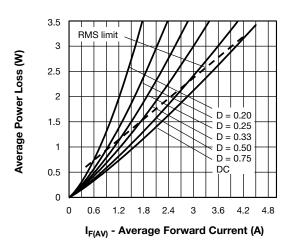


Fig. 5 - Forward Power Loss Characteristics

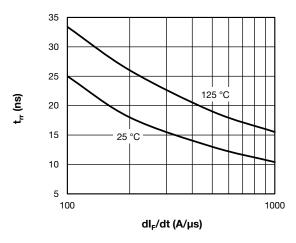


Fig. 6 - Typical Reverse Recovery vs. dl<sub>F</sub>/dt

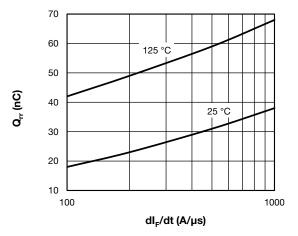


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see Fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{rated } V_R \\ \end{array}$ 

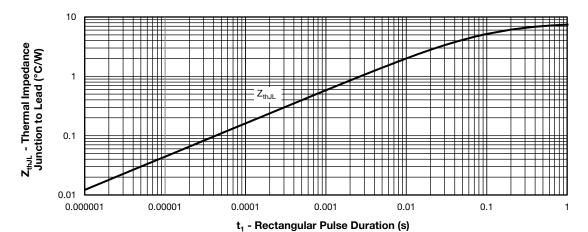


Fig. 8 - Typical Thermal Impedance Z<sub>thJL</sub> Junction-to-Lead

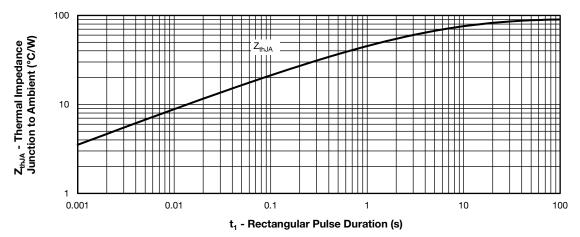
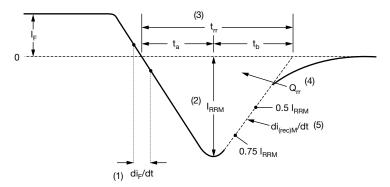


Fig. 9 - Typical Thermal Impedance  $Z_{thJA}$  Junction-to-Ambient



- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_F$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{rr}$  area under curve defined by  $\mathbf{t}_{rr}$  and  $\mathbf{I}_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) di<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

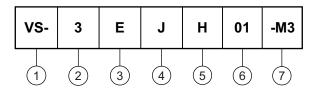
Fig. 10 - Reverse Recovery Waveform and Definitions



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### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating (3 = 3 A)

3 - Circuit configuration:

E = single diode

4 - J = SlimSMA package

5 - Process type,

H = hyperfast recovery

6 - Voltage code (01 = 100 V)

7 - -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-3EJH01-M3/6A	3500	3500	7"diameter plastic tape and reel		
VS-3EJH01-M3/6B	14 000	14 000	13"diameter plastic tape and reel		

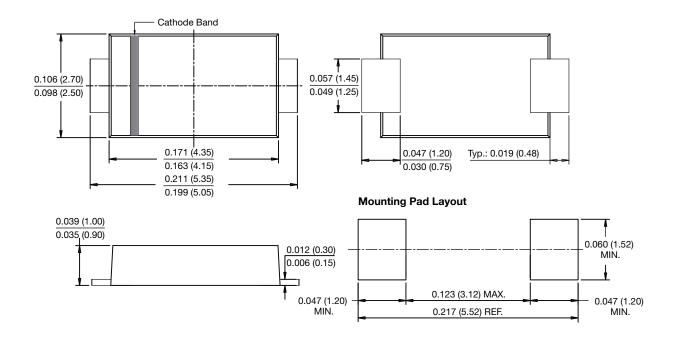
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95771</u>				
Part marking information	www.vishay.com/doc?95562			
Packaging information	www.vishay.com/doc?88869			



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# DO-221AC (SlimSMA)

## **DIMENSIONS** in inches (millimeters)





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